

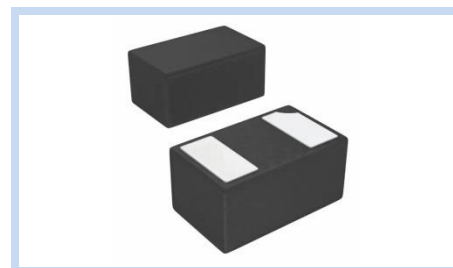
ESD Suppressor AEC-Q101 5V Unidirectional SOD-882

ME51U9V8S882A

MERITEK

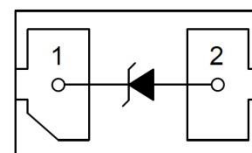
FEATURE

- IEC 61000-4-2 ESD: $\pm 15\text{KV}$ (Air) $\pm 8\text{KV}$ (Contact)
- ESD Protection for one Unidirectional Channel
- Low Leakage Current
- Low Clamping Voltage
- Solid-State Silicon-Avalanche Technology



APPLICATION

- USB 3.0/USB 2.0
- MHL/MIPI/MDDI
- HDMI, Video Port, eSATA
- Smart Phones
- External Storage



MAXIMUM RATINGS AND CHARACTERISTICS

Parameter	Symbol	Value	Unit
ESD Voltage (Contact discharge)	V_{ESD}	± 8	KV
ESD Voltage (Air discharge)		± 15	
Peak Pulse Current ($t_p=8/20\mu s$)	I_{PP}	4	A
Operating & Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

Parameter	Condition	Symbol	Min.	Typ.	Max.	Unit
Reverse Stand-Off Voltage	--	V_{RWM}	--	--	5	V
Reverse Breakdown Voltage	$I_{BR}=1\text{mA}$	V_{BR}	6	--	8.5	V
Reverse Leakage Current	$V_R=5\text{V}$	I_R	--	--	1	μA
Clamping Voltage	$I_{PP}=1\text{A}, t_p=8/20\mu s$	V_C	--	--	9.8	V
	$I_{PP}=4\text{A}, t_p=8/20\mu s$		--	--	15	
Clamping Voltage TLP	16A	V_C	--	24	--	V
Off State Junction Capacitance	$V_{dc}=0, f=1\text{MHz}$	C_J	--	0.6	--	pF

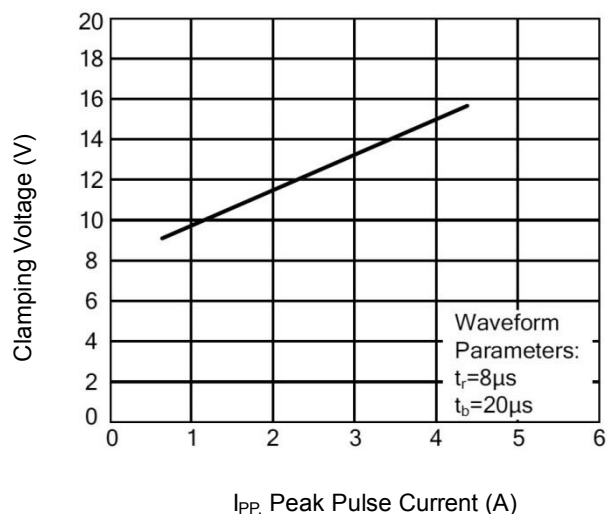
Notes:

1. $T_J=25^{\circ}\text{C}$ unless otherwise specified

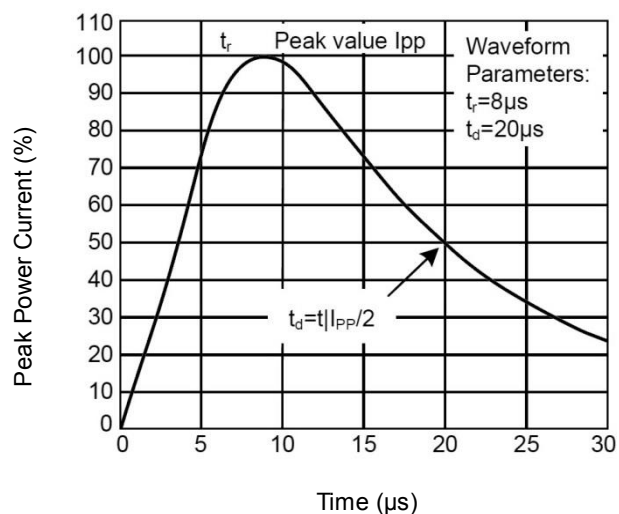
2. Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse(TLP) Model, See Figure 4.

CHARACTERISTIC CURVES

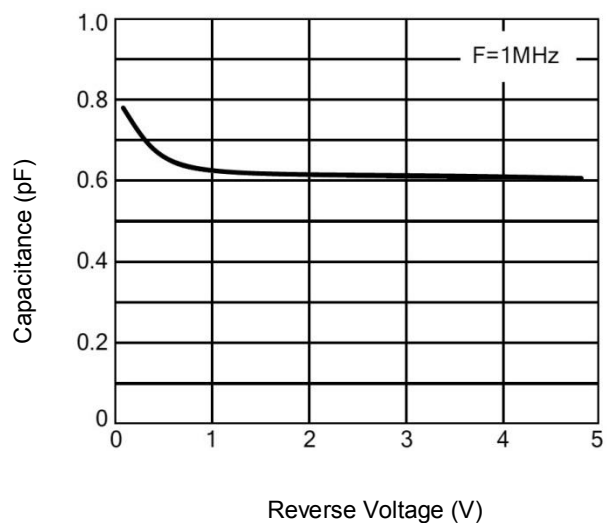
Clamping Voltage vs. Peak Pulse Current



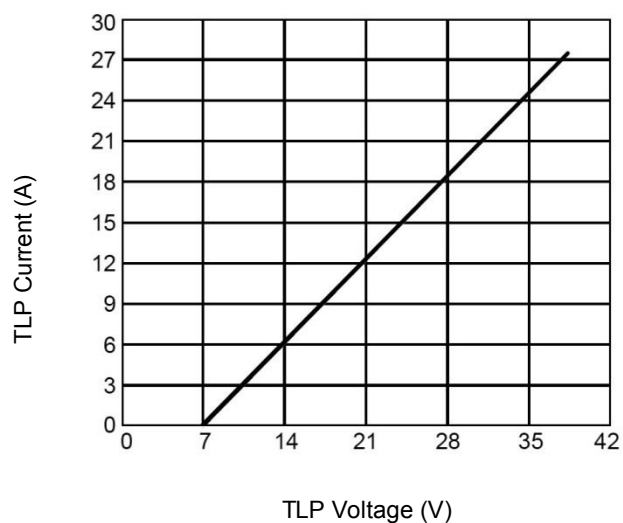
Pulse Waveforms



Capacitance vs. Reverse Voltage



TLP Measurement



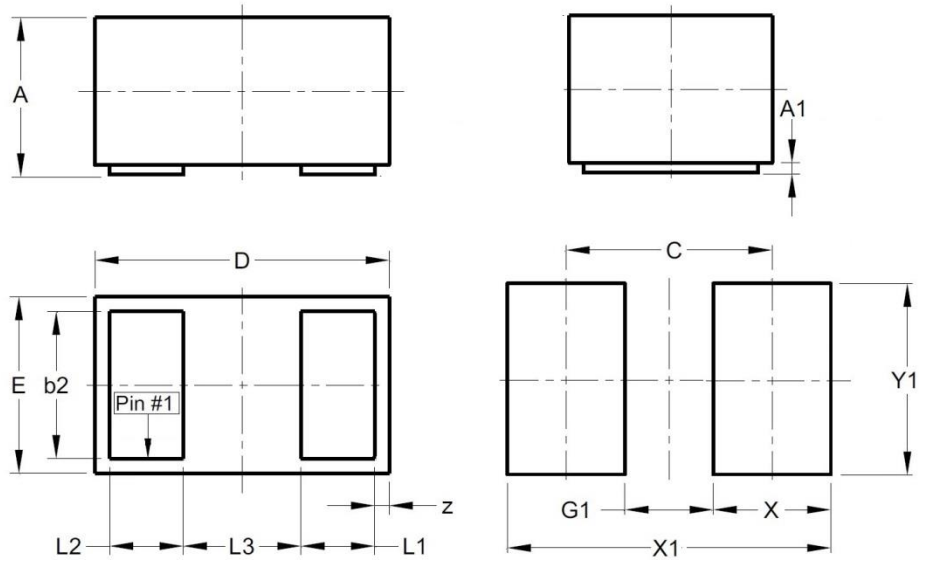
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DIMENSIONS AND RECOMMENDED LAND PATTERN

Item	Min (mm)	Max (mm)
A	0.32	0.55
A1	-	-
b2	0.45	0.55
D	0.95	1.05
E	0.55	0.65
z	0.05	0.05
L1	0.20	0.30
L2	0.20	0.30
L3	0.40	0.40
C	0.85	0.85
G1	0.30	0.30
X	0.55	0.55
X1	1.40	1.40
Y1	0.60	0.60



*Specifications subject to change without notice